

TECHNICAL DATA DATASHEET 4751, REV. B

SILICON SCHOTTKY RECTIFIER Ultra Low Reverse Leakage 175°C Operating Temperature

Applications:

• Switching Power Supply • Converters • Free-Wheeling Diodes • Polarity Protection Diode

Features:

- Ultra low Reverse Leakage Current
- Soft Reverse Recovery at Low and High Temperature
- Very Low Forward Voltage Drop
- Low Power Loss, High Efficiency
- High Surge Capacity
- Guard Ring for Enhanced Durability and Long Term Reliability
- Guaranteed Reverse Avalanche Characteristics

Maximum Ratings:

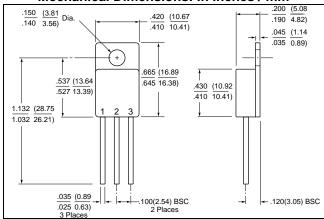
Characteristics	Symbol	Condition	Max.	Units
Peak Inverse Voltage	V_{RWM}	-	30	V
Max. Average Forward Current	I _{F(AV)}	Maximum DC Output Current (@ T _C =100 °C) (Single, Doubler)	7.5	A
Max. Average Forward Current	I _{F(AV)}	Maximum DC Output Current (@ T _C =100 ^O C) (Common Cathode, Common Anode)	15	А
Max. Peak One Cycle Non- Repetitive Surge Current	I _{FSM}	8.3 ms, half Sine wave	75	Α
Maximun Thermal Resistence (Per leg)	$R_{\theta JC}$	-	5.37	°C/W
Max. Junction Temperature	TJ	-	-65 to +175	°C
Max. Storage Temperature	T _{stg}	-	-65 to +175	°C

Electrical Characteristics Per Leg

Characteristics	Symbol	Condition	Max.	Units
Max. Forward Voltage Drop	V_{F1}	@ 7.5 A, Pulse, T _J = 25 °C	0.58	V
	V_{F2}	@ 7.5 A, Pulse, T _J = 125 °C	0.48	V
Max. Reverse Current	I _{R1}	@V _R = 30 V, Pulse,	1	mA
		T _J = 25 °C		
	I _{R2}	@V _R = 30 V, Pulse,	50	mA
		T _J = 125 °C		
Max. Junction Capacitance	C _T	$@V_R = 5V, T_C = 25 ^{\circ}C$	550	pF
		$f_{SIG} = 1MHz,$		
		$V_{SIG} = 50 \text{mV (p-p)}$		

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Mechanical Dimensions: In Inches / mm



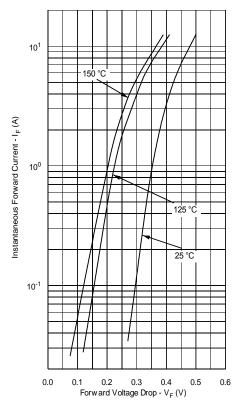
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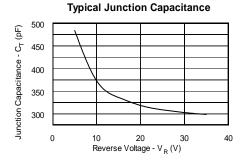
DEVICE TYPE	PIN 1	PIN 2	PIN 3
SINGLE RECTIFIER	CATHODE	ANODE	ANODE
COMMON CATHODE (P)	ANODE 1	COMMON CATHODE	ANODE 2
COMMON ANODE (N)	CATHODE 1	COMMON ANODE	CATHODE 2
DOUBLER (D)	ANODE	CATHODE / ANODE	CATHODE

10²

Typical Forward Characteristics

Typical Reverse Characteristics





20

Reverse Voltage - V_R (V)

40

0

SENSITRON

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Note: Vf characteristics are for unpackaged die only.

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